



T-46-07-11

## MM54HC573/MM74HC573 TRI-STATE® Octal D-Type Latch

### General Description

These high speed octal D-type latches utilize advanced silicon-gate CMOS technology. They possess the high noise immunity and low power consumption of standard CMOS integrated circuits, as well as the ability to drive 15 LS-TTL loads. Due to the large output drive capability and the TRI-STATE feature, these devices are ideally suited for interfacing with bus lines in a bus organized system.

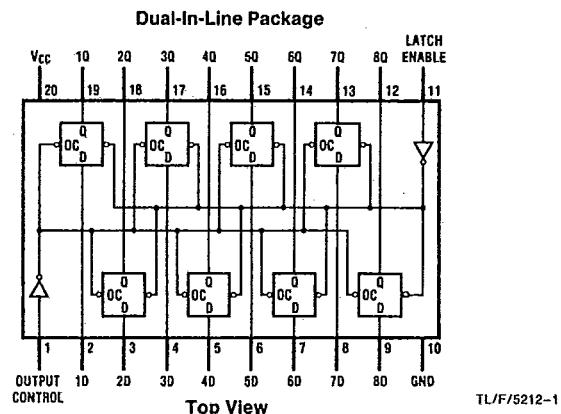
When the LATCH ENABLE(LE) input is high, the Q outputs will follow the D inputs. When the LATCH ENABLE goes low, data at the D inputs will be retained at the outputs until LATCH ENABLE returns high again. When a high logic level is applied to the OUTPUT CONTROL OC input, all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage elements.

The 54HC/74HC logic family is speed, function and pinout compatible with the standard 54LS/74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V<sub>CC</sub> and ground.

### Features

- Typical propagation delay: 13 ns
- Wide operating voltage range: 2 to 6 volts
- Low input current: 1  $\mu$ A maximum
- Low quiescent current: 80  $\mu$ A maximum (74HC Series)
- Compatible with bus-oriented systems
- Output drive capability: 15 LS-TTL loads

### Connection Diagram



Order Number MM54HC573\* or MM74HC573\*

\*Please look into Section 8, Appendix D for availability of various package types.

### Truth Table

Output Control	Latch Enable	Data	Output
L	H	H	H
L	H	L	L
L	L	X	Q <sub>0</sub>
H	X	X	Z

H = high level, L = low level

Q<sub>0</sub> = level of output before steady-state input conditions were established.

Z = high impedance

X = Don't care

MM54HC573/MM74HC573

**Absolute Maximum Ratings** (Notes 1 & 2)

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage ( $V_{CC}$ )	-0.5 to +7.0V
DC Input Voltage ( $V_{IN}$ )	-1.5 to $V_{CC}$ + 1.5V
DC Output Voltage ( $V_{OUT}$ )	-0.5 to $V_{CC}$ + 0.5V
Clamp Diode Current ( $I_{IK}, I_{OK}$ )	$\pm 20$ mA
DC Output Current, per pin ( $I_{OUT}$ )	$\pm 35$ mA
DC $V_{CC}$ or GND Current, per pin ( $I_{CC}$ )	$\pm 70$ mA
Storage Temperature Range ( $T_{STG}$ )	-65°C to +150°C
Power Dissipation ( $P_D$ ) (Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature ( $T_L$ ) (Soldering 10 seconds)	260°C

**Operating Conditions**

	Min	Max	Units
Supply Voltage ( $V_{CC}$ )	2	6	V
DC Input or Output Voltage ( $V_{IN}, V_{OUT}$ )	0	$V_{CC}$	V
Operating Temp. Range ( $T_A$ )			
MM74HC	-40	+85	°C
MM54HC	-55	+125	°C
Input Rise or Fall Times ( $t_r, t_f$ )			
$V_{CC} = 2.0V$	1000	ns	
$V_{CC} = 4.5V$	500	ns	
$V_{CC} = 6.0V$	400	ns	

**DC Electrical Characteristics** (Note 4)

Symbol	Parameter	Conditions	$V_{CC}$	$T_A = 25^\circ C$		$74HC$	$54HC$	Units
				Typ	Guaranteed Limits			
$V_{IH}$	Minimum High Level Input Voltage		2.0V	1.5	1.5	1.5	1.5	V
			4.5V	3.15	3.15	3.15	3.15	V
			6.0V	4.2	4.2	4.2	4.2	V
$V_{IL}$	Maximum Low Level Input Voltage**		2.0V	0.5	0.5	0.5	0.5	V
			4.5V	1.35	1.35	1.35	1.35	V
			6.0V	1.8	1.8	1.8	1.8	V
$V_{OH}$	Minimum High Level Output Voltage	$V_{IN} = V_{IH}$ or $V_{IL}$ $ I_{OUT}  \leq 20 \mu A$	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
$V_{OL}$	Maximum Low Level Output Voltage	$V_{IN} = V_{IH}$ or $V_{IL}$ $ I_{OUT}  \leq 6.0 \text{ mA}$	4.5V	4.2	3.98	3.84	3.7	V
		$ I_{OUT}  \leq 7.8 \text{ mA}$	6.0V	5.7	5.48	5.34	5.2	V
$I_{IN}$	Maximum Input Current	$V_{IN} = V_{CC}$ or GND	6.0V	$\pm 0.1$	$\pm 1.0$	$\pm 1.0$	$\pm 1.0$	$\mu A$
$I_{OZ}$	Maximum TRI-STATE Output Leakage Current	$V_{OUT} = V_{CC}$ or GND $OC = V_{IH}$	6.0V	$\pm 0.5$	$\pm 5.0$	$\pm 10$	$\pm 10$	$\mu A$
$I_{CC}$	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND $I_{OUT} = 0 \mu A$	6.0V	8.0	80	160	160	$\mu A$

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: -12 mW/°C from 65°C to 85°C; ceramic "J" package: -12 mW/°C from 100°C to 125°C.

Note 4: For a power supply of 5V ± 10% the worst-case output voltages ( $V_{OH}$  and  $V_{OL}$ ) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst-case  $V_{IH}$  and  $V_{IL}$  occur at  $V_{CC} = 5.6V$  and 4.5V respectively. (The  $V_{IH}$  value at 5.6V is 3.85V.) The worst-case leakage current ( $I_{IN}$ ,  $I_{CC}$ , and  $I_{OZ}$ ) occur for CMOS at the higher voltage and so the 6.0V values should be used.\*\* $V_{IL}$  limits are currently tested at 20% of  $V_{CC}$ . The above  $V_{IL}$  specification (30% of  $V_{CC}$ ) will be implemented no later than Q1, CY'89.

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AC Electrical Characteristics  $V_{CC} = 5V, T_A = 25^\circ C, t_r = t_f = 6 \text{ ns}$ 

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Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
$t_{PHL}, t_{PLH}$	Maximum Propagation Delay, Data to Q	$C_L = 45 \text{ pF}$	12	19	ns
$t_{PHL}, t_{PLH}$	Maximum Propagation Delay, LE to Q	$C_L = 45 \text{ pF}$	12	20	ns
$t_{PZH}, t_{PZL}$	Maximum Output Enable Time	$R_L = 1 \text{ k}\Omega$ $C_L = 45 \text{ pF}$	13	25	ns
$t_{PHZ}, t_{PLZ}$	Maximum Output Disable Time	$R_L = 1 \text{ k}\Omega$ $C_L = 5 \text{ pF}$	11	20	ns
$t_S$	Minimum Set Up Time, Data to LE		10	15	ns
$t_H$	Minimum Hold Time, LE to Data		2	5	ns
$t_W$	Minimum Pulse Width, LE or Data		10	16	ns

## AC Electrical Characteristics

Symbol	Parameter	Conditions	$V_{CC}$	$T_A = 25^\circ C$		$74HC$	$54HC$	Units
				Typ	Guaranteed Limits			
$t_{PHL}, t_{PLH}$	Maximum Propagation Delay Data to Q	$C_L = 50 \text{ pF}$	2.0V	45	110	138	165	ns
		$C_L = 150 \text{ pF}$	2.0V	58	150	188	225	ns
		$C_L = 50 \text{ pF}$	4.5V	14	22	28	33	ns
$t_{PHL}, t_{PLH}$	Maximum Propagation Delay, Latch Enable to Q	$C_L = 150 \text{ pF}$	4.5V	21	30	38	40	ns
		$C_L = 50 \text{ pF}$	6.0V	12	19	24	29	ns
		$C_L = 150 \text{ pF}$	6.0V	19	26	33	39	ns
$t_{PZH}, t_{PZL}$	Maximum Output Enable Time	$R_L = 1 \text{ k}\Omega$						
		$C_L = 50 \text{ pF}$	2.0V	46	115	143	173	ns
		$C_L = 150 \text{ pF}$	2.0V	60	155	194	233	ns
$t_{PZH}, t_{PZL}$	Maximum Output Disable Time	$C_L = 50 \text{ pF}$	4.5V	14	23	29	35	ns
		$C_L = 150 \text{ pF}$	4.5V	21	31	47	47	ns
		$C_L = 50 \text{ pF}$	6.0V	12	20	25	30	ns
$t_{PZH}, t_{PZL}$	Maximum Output Disable Time	$C_L = 150 \text{ pF}$	6.0V	19	27	34	41	ns
		$R_L = 1 \text{ k}\Omega$						
		$C_L = 50 \text{ pF}$	2.0V	55	140	175	210	ns
$t_{PZH}, t_{PZL}$	Maximum Output Enable Time	$C_L = 150 \text{ pF}$	2.0V	67	180	225	270	ns
		$C_L = 50 \text{ pF}$	4.5V	15	28	35	42	ns
		$C_L = 150 \text{ pF}$	4.5V	24	36	45	54	ns
$t_{PZH}, t_{PZL}$	Maximum Output Disable Time	$C_L = 50 \text{ pF}$	6.0V	14	24	30	36	ns
		$C_L = 150 \text{ pF}$	6.0V	22	31	39	47	ns
		$R_L = 1 \text{ k}\Omega$						
$t_S$	Minimum Set Up Time Data to LE	$C_L = 50 \text{ pF}$	2.0V	40	125	156	188	ns
		$C_L = 150 \text{ pF}$	4.5V	13	25	31	38	ns
		$C_L = 50 \text{ pF}$	6.0V	12	21	27	32	ns
$t_H$	Minimum Hold Time LE to Data							
		$C_L = 50 \text{ pF}$	2.0V	25	31	38	38	ns
		$C_L = 150 \text{ pF}$	4.5V	5	6	7	7	ns
$t_W$	Minimum Pulse Width LE, or Data							
		$C_L = 50 \text{ pF}$	2.0V	30	80	100	120	ns
		$C_L = 150 \text{ pF}$	4.5V	9	16	20	24	ns
$t_{TLH}, t_{THL}$	Maximum Output Rise and Fall Time, Clock	$C_L = 50 \text{ pF}$	6.0V	8	14	18	20	ns
		$C_L = 150 \text{ pF}$	2.0V	25	60	75	90	ns
		$C_L = 50 \text{ pF}$	4.5V	7	12	15	18	ns
$C_{PD}$	Power Dissipation Capacitance (Note 5) (per latch)	$OC = V_{CC}$		30				pF
		$OC = GND$		50				pF
$C_{IN}$	Maximum Input Capacitance			5	10	10	10	pF
$C_{OUT}$	Maximum Output Capacitance			15	20	20	20	pF

Note 5:  $C_{PD}$  determines the no load dynamic power consumption,  $P_0 = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ , and the no load dynamic current consumption,  $I_S = C_{PD} V_{CC} f + I_{CC}$ .